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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/076,003	02/14/2002	Paul F. Baude	57181US002	9203

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EXAMINER

TRINH, HOA B

ART UNIT	PAPER NUMBER
2814	

DATE MAILED: 03/28/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

**Office Action Summary**

Application No.

10/076,003

Applicant(s)

BAUDE ET AL.

Examiner

Vikki H Trinh

Art Unit

2814

— The MAILING DATE of this communication appears on the cover sheet with the correspondence address —  
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

**Status**

1) Responsive to communication(s) filed on \_\_\_\_\_.

2a) This action is FINAL.      2b) This action is non-final.

3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

**Disposition of Claims**

4) Claim(s) 1-38 is/are pending in the application.

4a) Of the above claim(s) 1-19 and 34-38 is/are withdrawn from consideration.

5) Claim(s) \_\_\_\_\_ is/are allowed.

6) Claim(s) 20-33 is/are rejected.

7) Claim(s) \_\_\_\_\_ is/are objected to.

8) Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

**Application Papers**

9) The specification is objected to by the Examiner.

10) The drawing(s) filed on \_\_\_\_\_ is/are: a) accepted or b) objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).

11) The proposed drawing correction filed on \_\_\_\_\_ is: a) approved b) disapproved by the Examiner.  
If approved, corrected drawings are required in reply to this Office action.

12) The oath or declaration is objected to by the Examiner.

**Priority under 35 U.S.C. §§ 119 and 120**

13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  
a) All b) Some \* c) None of:  
1. Certified copies of the priority documents have been received.  
2. Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.  
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  
\* See the attached detailed Office action for a list of the certified copies not received.

14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).  
a) The translation of the foreign language provisional application has been received.

15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

**Attachment(s)**

1) Notice of References Cited (PTO-892)

2) Notice of Draftsperson's Patent Drawing Review (PTO-948)

3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 2-3-5.

4) Interview Summary (PTO-413) Paper No(s). \_\_\_\_\_.

5) Notice of Informal Patent Application (PTO-152)

6) Other: \_\_\_\_\_.

## DETAILED ACTION

### *Election/Restrictions*

1. Applicant's election with traverse of Group II in Paper No. 6 is acknowledged. The traversal is on the ground(s) that group I and IV should be examined together along with group III, because the groups are from the same class. This is not found persuasive because the groups represent different distinct inventions. For example, Group I states a deposition system; Group III indicates an integrated circuit; and Group IV states a transistor.

The requirement is still deemed proper and is therefore made FINAL.

### *Claim Objections*

2. Claim 20 is objected to because of the following informalities: Claim 20, line 7, "each patterned layer" is vague and unclear, because it is not clear as to which layer applicant is referring to. Appropriate correction is required.

### *Claim Rejections - 35 USC § 102*

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

4. Claims 20-22, 25-33 are rejected under 35 U.S.C. 102(b) as being anticipated by Sturm et al. (6,087,196).

As to claim 20, Sturm et al. (6,087,196) discloses a deposition substrate 116, a patterned first electrode layer 118 adjacent the substrate; a patterned organic semiconductor layer 120; and

a second patterned electrode layer 124, 126, wherein the patterned layer is defined by repositionable aperture mask. See figures 14B-14C.

As to claim 21, the first electrode layer defines a gate electrode 118 and the second electrode layer defines S/D electrodes 124, 126. See figures 14B-14C.

As to claim 22, the first electrode 124, 126 defines the S?D electrodes and the second electrode layer 118 defines a gate electrode. See figures 14B.

As to claim 25, the organic semiconductor is a polycrystalline organic semiconductor. See column 6, lines 50-68.

As to claim 26, the material is pentacene. See column 6, lines 50-65.

As to claim 27, one or more complimentary transistor circuit elements 108, 110, 112. See figures 13C.

As to claim 28, the elements include a semiconductor layer 102, 104, 106, having amorphous semiconductor layer. See column 6, lines 40-50.

As to claims 29-31, an interconnect layer 122. See figure 14B.

As to claim 32, a patterned dielectric layer 122 formed adjacent to the organic layer 120.

See figure 14B.

As to claim 33, the IC is an electronic display. See column 3, lines 55-60.

Claim Rejections - 35 USC § 103

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

2. The factual inquiries set forth in *Graham v. John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

1. Determining the scope and contents of the prior art.
2. Ascertaining the differences between the prior art and the claims at issue.
3. Resolving the level of ordinary skill in the pertinent art.
4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

3. Claims 23-24 are rejected under 35 U.S.C. 103(a) as being unpatentable over *Sturns et al. (6,087,196)*.

*Sturns et al. (6,087,196)* discloses the invention substantially as claimed. However, *Sturns et al. (6,087,196)* does not teach a specific range of gap between the S/D electrodes. Nonetheless, it would have been obvious to one skilled in the art at the time the invention was made to modify the gap between the s/d electrodes of *Sturns et al. (6,087,196)* with the specific

range, as claimed, since it is *prima facie* obvious of an artisan's experimentation and optimization because applicant has not established any criticality for the specific range.

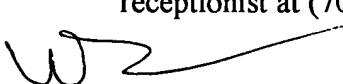
The courts have concluded that there is no requirement that a motivation to make the modification be expressly articulated. The test for combining references is what the combination of disclosures taken as a whole would suggest to one of ordinary skill in the art. *In re McLaughlin*, 170 USPQ 209 (CCPA 1971). Also, references are evaluated by what they suggest to one versed in the art, rather than by their specific disclosures. *In re Bozek*, 163 USPQ 545 (CCPA 1969).

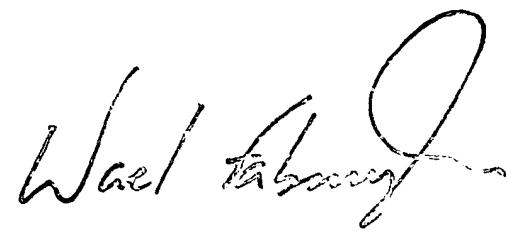
### Conclusion

4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Katz discloses an organic semiconductor layer with gate electrode and other elements. See entire document.

5. Any inquiry concerning this communication or earlier communications from the Examiner should be directed to Vikki Trinh whose telephone number is (703) 308-8238. The Examiner can normally be reached Mon-Tuesday, Thurs-Friday, 7:30 AM - 6:00 PM Eastern Time. If attempts to reach the examiner by telephone are unsuccessful, the Examiner's supervisor, Mr. Wael Fahmy, can be reached at (703) 308-4918. General inquiries relating to the status of this application should be directed to the Group receptionist at (703) 308-0858. The fax number is (703) 308-2708.

  
Vikki Trinh,  
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